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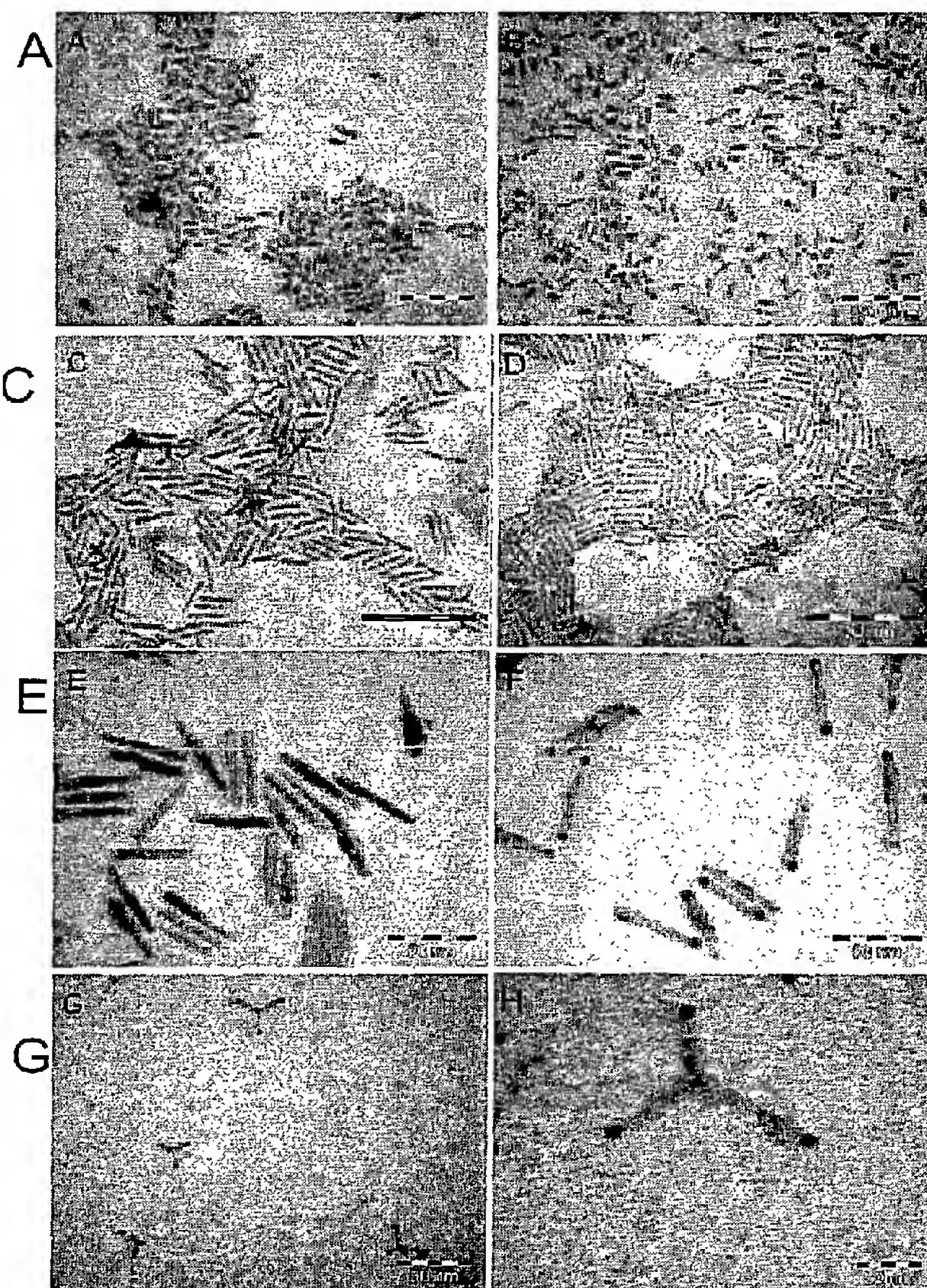
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(54) Title: NOVEL NANOSTRUCTURES AND METHOD FOR SELECTIVE PREPARATION



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(57) Abstract: The present invention provides novel
nanostructure composed of at least one elongated
structure element, an elongated structure element
of said nanostructure bearing a different zone
made of metal, metal alloy, conductive polymer or
semiconductor and selectively grown onto at least
one of the end portions of the elongated structure
element. The present invention further provides a
selective method for forming in a liquid medium, such
nanostructures.

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